MN37230FT

6.0mm (type-1/3) CCD Area Image Sensor

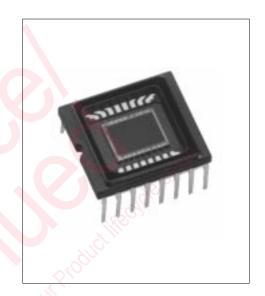
■ Overview

The MN37230FT is a 6.0mm (type-1/3) interline transfer CCD (IT-CCD) solid state image sensor device.

This device uses photodiodes in the optoelectric conversion section and CCDs for signal read out. The electronic shutter function has made an exposure time of 1/10000 seconds possible. Further, this device has the features of high sensitivity, low noise, broad dynamic range, and low smear.

This device has a total of 661,024 pixels (908 horizontal × 728 vertical) and provides stable and clear images with a resolution of 430 horizontal TV-lines and 420 vertical TV-lines.

Part Number	Size	System	Color or B/W
MN37230FT	6.0mm(type-1/3)	PAL	Color



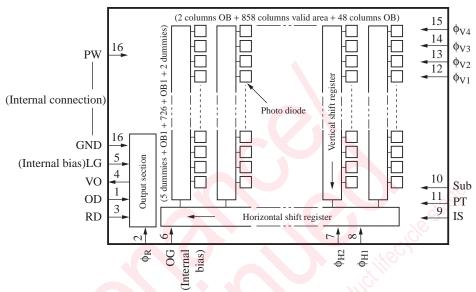
■ Features

- High sensitivity
- Low noise
- Broad dynamic range
- Low smear
- Low image lag
- Electronic shutter
- No image distortion
- Small size enables design of compact equipment
- High reliability
- 16-pin plastic package

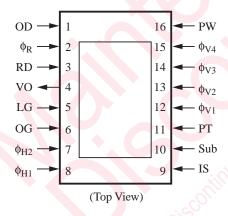
Applications

 Compact lightweight camcorders. Cameras for surveillance, measurement, and medical use

■ Block Diagram



■ Pin Assignments



■ Pin Descriptions

Pin No.	Symbol	Descriptions	Pin No.	Symbol	Descriptions
1	OD	Output drain	11	PT	P-well for protection circuit
2	φ _R	Reset pulse	12	ϕ_{V1}	Vertical shift register
3	RD	Reset drain	Kin		clock pulse 1
4	VO	Video output	13	φ _{V2}	Vertical shift register
5	LG	Output load transistor gate			clock pulse2
6	OG	Output gate	14	φ _{V3}	Vertical shift register
7	φ _{H2}	Horizontal register clock pulse 2			clock pulse 3
8	фн1	Horizontal register clock pulse 1	15	ϕ_{V4}	Vertical shift register
9	IS	Horizontal CCD input source			clock pulse 4
10	Sub	Substrate	16	PW	P-well

2 Panasonic

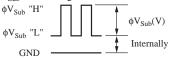
■ Absolute Maximum Ratings and Operating Conditions

Parameter		0 1 1	Rating		Operating condition			11.2	
		Symbol	min	max	min	typ	max	Unit	
Reset drain voltage		V_{RD}	- 0.2	18.0	14.5	15.0	15.5	V	
Output drain volt	Output drain voltage		- 0.2	18.0	14.5	15.0	15.5	V	
Output load transistor gate voltage		V_{LG}		Supplied internally					
Output gate volta	Output gate voltage			Supplied internally					
Horizontal CCD input s	Horizontal CCD input source voltage		-0.2 18.0		14.5	15.0	15.5	V	
Protection P-well voltage		V _{PT} *2	-10.0	0.2	φ _{V(L)} - 1.2	φ _{V(L)} - 1.0	φ _{V(L)} - 0.7	V	
P-well voltage		V_{PW}	Reference voltage			0	300	V	
Reset	H-L	$V_{\phi R(H-L)}$		18.0	4.7	5.0	5.3	V	
pulse voltage	Bias	$V_{\phi R(Bias)}$		Sup	plied interr)	V		
Horizontal register		$V_{\phi H1(H)}$		18.0	4.7	5.0	5.3	V	
clock pulse volta	clock pulse voltage 1		- 0.3		- 0.2	0	0.2		
Horizontal register		V _{oH2(H)}	_	18.0	4.7	5.0	5.3	V	
clock pulse voltage 2		$V_{\phi H2(L)}$	- 0.2	- 40	0	0	0		
Vertical shift regi	Vertical shift register		_	18.0	14.5	15.0	15.5	Q.	
clock pulse voltage 1		V _{\phiV1(M)} *2		10 L	-0.2	0	0.2		
		V _{\phiV1(L)} *2	- 9.0	<u> </u>	-7.3	7.0	- 6.7		
Vertical shift regi	ertical shift register		1.60	15.0	- 0.2	0	0.2	V	
clock pulse volta	ge 2	V _{\(\phi\V2(L)\)} *2	- 9.0		-7.3	- 7.0	- 6.7		
Vertical shift regi	ster	V _{\phiV3(H)} *2	(P)	18.0	14.5	15.0	15.5	V	
clock pulse voltage 3		V _{\phiV3(M)} *2	3, -1,0	100	- 0.2	0 0	0.2		
			- 9.0	so-c	-7.3	-7.0	- 6.7		
Vertical shift regi	ster	V _{\phiV4(M)} *2	40	15.0	-0.2	0	0.2	V	
clock pulse voltage	ge 4	V _{\phiV4(L)} *2	- 9.0	- 4	- 7.3	- 7.0	- 6.7		
Substrate voltage	Substrate voltage		Supplied internally					V	
			- 0.2	45.0	24.2	25.0	25.8		
Operating temper	rature	T_{opr}	-10	70	_	25	_	°C	
Storage temperat	ure	$T_{\rm stg}$	-30	80	_		_	°C	

Note)1. Standard light input defines

Standard light input is the one when the exposure is done at a lens aperture of F8, using a light source of $2856 \, \text{K}$ and $1050 \, \text{nt}$, and placing a color temperature conversion filter LB-40 (HOYA) and an IR cutting filter CAW-500 (t = $2.5 \, \text{mm}$) in the light path.

- 2. *1: V_{Sub} internal settings guarantee blooming at 400 times light input of the standard light input.
- 3. *2: V_{PT} is set so that the following conditions are set for VL of the vertical shift clock. $V_{PT} \subseteq VL$
- 4. *3: V_{Sub} when using electronic shutter function



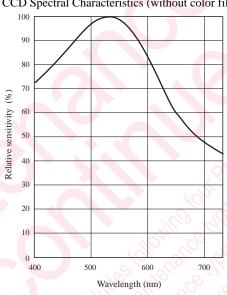
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■ Optical Characteristics

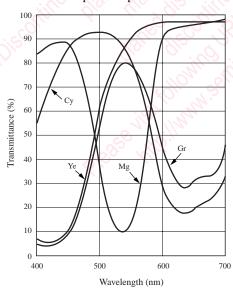
Part Number	Color or	Effec		S/N typ	Saturation output typ	Sensitivity F8 typ	Vertical smear Sm	Image lag typ	Horizontal resolution typ	Vertical resolution typ
	B/W	Н	V	(dB)	(mV)	(mV)	typ(%)	(%)	(TV-lines)	(TV-lines)
MN37230FT	Color	858	726	60	500	180	0.02	_	430	420

■ Graphs of Characteristics

CCD Spectral Characteristics (without color filter)

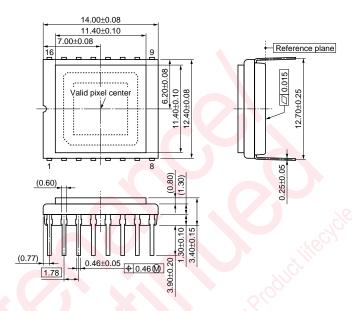


CCD On-Chip Filter Spectral Characteristics



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- Package Dimensions (Unit:mm)
- WDIP016-P-0500C



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